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## 2:1 DIFFERENTIAL-TO-LVDS MULTIPLEXER

## ICS85401

## Description

ICS HiPerClockS™ The ICS85401 is a high performance 2:1 Differential-to-LVDS Multiplexer and a member of the HiPerClockS<sup>™</sup>family of High Performance Clock Solutions from ICS. The ICS85401 can also perform differential translation because the differ-ential

inputs accept LVPECL, CML as well as LVDS levels. The ICS85401 is packaged in a small 3mm x 3mm 16 VFQFN package, making it ideal for use on space constrained boards.

## **Features**

- 2:1 LVDS MUX
- One LVDS output pair
- Two differential clock inputs can accept: LVPECL, LVDS, CML
- Maximum input/output frequency: 2.5GHz
- Translates LVCMOS/LVTTL input signals to LVDS levels by using a resistor bias network on nCLK0, nCLK1
- Propagation delay: 460ps (maximum)
- Part-to-part skew: 100ps (maximum)
- Full 3.3V supply mode
- -40°C to 85°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

## **Block Diagram**



## **Pin Assignment**



#### ICS85401

16-Lead VFQFN 3mm x 3mm x 0.95mm package body K Package Top View

Table	1.	Pin	Descriptions
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Number	Name	Т	уре	Description
1	CLK0	Input	Pulldown	Non-inverting differential clock input.
2	<u>CLK0</u>	Input	Pullup/ Pulldown	Inverting differential clock input. VDD/2 default when left floating.
3	CLK1	Input	Pulldown	Non-inverting differential clock input.
4	CLK1	Input	Pullup/ Pulldown	Inverting differential clock input. VDD/2 default when left floating.
5, 7, 16	nc	Unused		No connect.
6	CLK_SEL	Input	Pulldown	Clock select input. When HIGH, selects CLK1, CLK1 inputs. When LOW, selects CLK0, CLK0 inputs. LVCMOS / LVTTL interface levels.
8, 13	V <sub>DD</sub>	Power		Power supply pins.
9, 12, 14, 15	GND	Power		Power supply ground.
10, 11	<u>Q</u> , Q	Output		Differential output pair. LVDS interface levels.

NOTE: Pullup and Pulldown refer to intenal input resistors. See Table 2, Pin Characteristics, for typical values.

## **Table 2. Pin Characteristics**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			1		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			37		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			37		kΩ

## **Function Tables**

Table 3. Control Input Function Table

Input	CLK_OUT
CLK_SEL	CLK
0	CLK0, CLK0
1	CLK1, CLK1

## Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characterisitcs* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V <sub>DD</sub>	4.6V
Inputs, V <sub>I</sub>	-0.5V to V <sub>DD</sub> + 0.5V
Outputs, I <sub>O</sub>	
Continous Current	10mA
Surge Current	15mA
Package Thermal Impedance, $\theta_{JA}$	51.5°C/W (0 lfpm)
Storage Temperature, T <sub>STG</sub>	-65°C to 150°C

## **DC Electrical Characteristics**

#### Table 4A. Power Supply DC Characteristics, $V_{DD}$ = 3.3V ± 5%, $T_A$ = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Positive Supply Voltage		3.135	3.3	3.465	V
I <sub>DD</sub>	Power Supply Current				40	mA

#### Table 4B. LVCMOS/LVTTL DC Characteristics, $V_{DD}$ = 3.3V $\pm$ 5%, $T_{A}$ = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V <sub>IH</sub>	Input High Voltage			2		V <sub>DD</sub> + 0.3	V
V <sub>IL</sub>	Input Low Voltage			-0.3		0.8	V
I <sub>IH</sub>	Input High Current	CLK_SEL	$V_{DD} = V_{IN} = 3.465V$			150	μΑ
IIL	Input Low Current	CLK_SEL	V <sub>DD</sub> = 3.465V, V <sub>IN</sub> = 0V	-150			μA

#### Table 4C. Differential DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ , $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
		CLK0, CLK1	$V_{DD} = V_{IN} = 3.465 V$			150	μA
ΊΗ	Input High Current	CLKO, CLK	$V_{DD} = V_{IN} = 3.465V$			150	μA
I <sub>IL</sub>	Input Low Current	CLK0, CLK1	$V_{DD} = 3.465V,$ $V_{IN} = 0V$	-150			μΑ
		CLKO, CLK	$V_{DD} = 3.465V,$ $V_{IN} = 0V$	-150			μΑ
V <sub>PP</sub>	Peak-to-Peak Voltage			0.15	0.8	1.2	V
V <sub>CMR</sub>	Common Mode Input Voltage; NOTE 1, 2			1.2		V <sub>DD</sub>	V

NOTE 1: Common mode input voltage is defined as V<sub>IH</sub>.

NOTE 2: For single-ended applications, the maximum input voltage for CLKx,  $\overline{\text{CLKx}}$  is V<sub>DD</sub> + 0.3V.

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>OD</sub>	Differential Output Voltage		200	350	500	mV
$\Delta V_{OD}$	V <sub>OD</sub> Magnitude Change				50	mV
V <sub>OS</sub>	Offset Voltage		1.05	1.15	1.25	V
$\Delta V_{OS}$	V <sub>OS</sub> Magnitude Change				50	mV

#### Table 4D. LVDS DC Characteristics, $V_{DD}$ = 3.3V $\pm$ 5%, $T_{A}$ = -40°C to 85°C

## **AC Electrical Characteristics**

Table 5. AC Characteristics,  $V_{DD}$  = 3.3V  $\pm$  5%,  $T_{A}$  = -40°C to 85°C

Parameter	Symbol	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency				>2.5	GHz
t <sub>PD</sub>	Propagation Delay; NOTE 1		260	360	460	ps
<i>t</i> sk(pp)	Part-to-Part Skew; NOTE 2, 3				100	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%	125	160	200	ps
odc	Output Duty Cycle		49		51	%
MUX_ISOLATION	MUX Isolation			-55		

All parameters measured at £ 1GHz unless otherwise noted.

NOTE 1: Measured from the differential input crossing point to the differential output crossing point.

NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65. Typical Phase Noise at 156.25MHz

## **Parameter Measurement Information**



3.3V LVDS Output Load AC Test Circuit



Part-to-Part Skew



**Output Duty Cycle/Pulse Width/Period** 







**Propagation Delay** 



**Output Rise/Fall Time** 

## Parameter Measurement Information, continued





**Offset Voltage Setup** 



## **Application Information**

## Wiring the Differential Input to Accept Single Ended Levels

*Figure 1* shows how the differential input can be wired to accept single ended levels. The reference voltage V\_REF =  $V_{DD}/2$  is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V\_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and  $V_{DD}$  = 3.3V, V\_REF should be 1.25V and R2/R1 = 0.609.



Figure 1. Single-Ended Signal Driving Differential Input

## **Differential Clock Input Interface**

The CLKx /CLKx accepts LVPECL, LVDS, CML and other differential signals. The signal must meet the V<sub>PP</sub> and V<sub>CMR</sub> input requirements. *Figures 2A to 2E* show interface examples for the HiPerClockS CLKx/CLKx input driven by the most common driver



Figure 2A. HiPerClockS CLK/CLK Input Driven by an IDT Open Collector CML Driver



Figure 2C. HiPerClockS CLK/CLK Input Driven by a 3.3V LVPECL Driver



Figure 2E. HiPerClockS CLK/CLK Input Driven by a 3.3V LVDS Drive

types. The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.



Figure 2B. HiPerClockS CLK/CLK Input Driven by a Built-In Pullup CML Driver



Figure 2D. HiPerClockS CLK/CLK Input Driven by a 3.3V LVPECL Driver with AC Couple

## **Recommendations for Unused Input Pins**

#### Inputs:

#### CLK/CLK Inputs:

For applications not requiring the use of the differential input, both CLK and  $\overline{\text{CLK}}$  can be left floating. Though not required, but for additional protection, a 1kW resistor can be tied from CLK to ground.

## **Application Schematic Example**

*Figure 3* shows an example of ICS85401 application schematic. This device can accept different types of input signal. In this

example, the input is driven by a LVDS driver. The decoupling capacitor should be located as close as possible to the power pin.



Figure 3. ICS85401 Application Schematic Example

#### Thermal Release Path

The expose metal pad provides heat transfer from the device to the P.C. board. The expose metal pad is ground pad connected to ground plane through thermal via. The exposed pad on the device to the exposed metal pad on the PCB is contacted through solder

as shown in *Figure 4*. For further information, please refer to the Application Note on Surface Mount Assembly of Amkor's Thermally /Electrically Enhance Leadframe Base Package, Amkor Technology.



Figure 4. P.C. Board for Exposed Pad Thermal Release Path Example

## **3.3V LVDS Driver Termination**

A general LVDS interface is shown in *Figure 5* In a  $100\Omega$  differential transmission line environment, LVDS drivers require a matched load termination of  $100\Omega$  across near the receiver input. For a

multiple LVDS outputs buffer, if only partial outputs are used, it is recommended to terminate the unused outputs.



Figure 5. Tyical LVDS Driver Termination

## **Power Considerations**

This section provides information on power dissipation and junction temperature for the ICS85401. Equations and example calculations are also provided.

#### 1. Power Dissipation.

The total power dissipation for the ICS85401 is the sum of the core power plus the analog power plus the power dissipated in the load(s). The following is the power dissipation for  $V_{DD} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

• Power\_MAX = V<sub>DD MAX</sub> \* I<sub>DD MAX</sub> = 3.465V \* 40mA = **138.6mW** 

#### 2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS devices is 125°C.

The equation for Tj is as follows: Tj =  $\theta_{JA}$  \* Pd\_total + T<sub>A</sub>

Tj = Junction Temperature

 $\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

Pd\_total = Total Device Power Dissipation (example calculation is in section 1 above)

T<sub>A</sub> = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming no air flow and a multi-layer board, the appropriate value is 51.5°C/W per Table 6 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

 $85^{\circ}C + 0.139W * 51.5^{\circ}C/W = 92.2^{\circ}C$ . This is well below the limit of  $125^{\circ}C$ .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (single layer or multi-layer).

#### Table 6. Thermal Resitance $\theta_{JA}$ for 16 Lead VFQFN, Forced Convection

$\theta_{JA}$ by Velocity				
Linear Feet per Minute	0			
Multi-Layer PCB, JEDEC Standard Test Boards	51.5°C/W			

## **Reliability Information**

## Table 7. $\theta_{\text{JA}}$ vs. Air Flow Table for a 16 Lead VFQFN

θ <sub>JA</sub> by Velocity					
Linear Feet per Minute	0				
Multi-Layer PCB, JEDEC Standard Test Boards	51.5°C/W				

#### **Transistor Count**

The transistor count for ICS85401 is: 132

## Package Outline and Package Dimension

#### Package Outline - K Suffix for 16 Lead VFQFN



#### **Table 8. Package Dimensions**

JEDEC Variation: VEED-2/-4 All Dimensions in Millimeters					
Symbol	Minimum Maximum				
N	16				
Α	0.80	1.00			
A1	0	0.05			
A3	0.25 Ref.				
b	0.18	0.30			
N <sub>D</sub> & N <sub>E</sub>	4				
D & E	3.00 Basic				
D2 & E2	1.00	1.80			
е	0.50 Basic				
L	0.30	0.50			

Reference Document: JEDEC Publication 95, MO-220

## **Ordering Information**

#### **Table 9. Ordering Information**

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
85401AK	401A	16 Lead VFQFN	Tube	-40°C to 85°C
85401AKT	401A	16 Lead VFQFN	2500 Tape & Reel	-40°C to 85°C
85401AKLF	01AL	"Lead-Free" 16 Lead VFQFN	Tube	-40°C to 85°C
85401AKLFT	01AL	"Lead-Free" 16 Lead VFQFN	2500 Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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## **Revision History Sheet**

Rev	Table	Page	Description of Change	Date
A		8	Add Schematic Layout.	8/23/04
A	Т8	10	Corrected count in Ordering Information Table.	11/17/04
А		1	Pin Assignment - corrected label on pin 2.	2/22/05
A	Т8	1 11	Features section - added Lead-Free bullet. Ordering Information Table - corrected Shipping Packaging from Tray to Tube, and added Lead-Free part number and note.	3/14/06
A	Т9	7 10 13	Corrected Differential Clock Input Interface. Added Power Considerations Section. Ordering Information Table - added Lead-Free marking. Updated format throughout the datasheet.	3/6/07

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